

Fast Rectifiers

ES2A-ES2D



SMB
CASE 403AF

Features

- For Surface Mount Applications
- Glass–Passivated Junction
- Low–Profile Package
- Easy Pick and Place
- Built–in Strain Relief
- Superfast Recovery Times for High Efficiency
- These are Pb–Free Devices

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage ES2A ES2B ES2C ES2D	50 100 150 200	V
$I_{F(AV)}$	Average Rectified Forward Current, 0.375" Lead Length at $T_L = 115^\circ\text{C}$	2.0	A
I_{FSM}	Non–Repetitive Peak Forward Surge Current, 8.3 ms Single Half–Sine Wave	50	A
T_{STG}	Storage Temperature Range	–55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature Range	–55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
P_D	Power Dissipation	1.66	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1)	75	$^\circ\text{C}/\text{W}$
$R_{\theta JL}$	Thermal Resistance, Junction to Lead (Note 1)	20	$^\circ\text{C}/\text{W}$

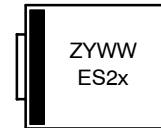
1. Device mounted on FR–4 PCB 0.013 mm.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Value				Unit
			ES2A	ES2B	ES2C	ES2D	
V_F	Maximum Forward Voltage	$I_F = 2.0\text{ A}$	0.90				V
t_{rr}	Reverse Recovery Time	$I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{RR} = 0.25\text{ A}$	20				ns
I_R	Maximum Reverse Current at Rated V_R	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	10 350				μA
C_T	Total Capacitance	$V_R = 4.0\text{ V}$, $f = 1.0\text{ MHz}$	18				pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MARKING DIAGRAM



(COLOR BAND DENOTES CATHODE)

Z = Assembly Plant Code
Y = Year
WW = Work Week
ES2x = Specific Device Code
x = A, B, C, D

ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

TYPICAL PERFORMANCE CHARACTERISTICS

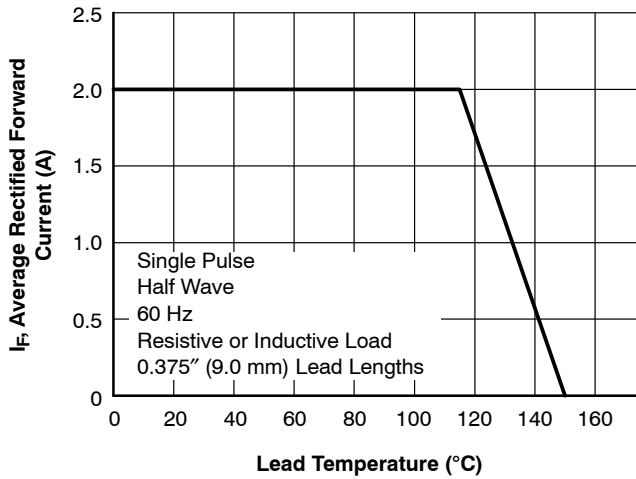


Figure 1. Forward Current Derating Curve

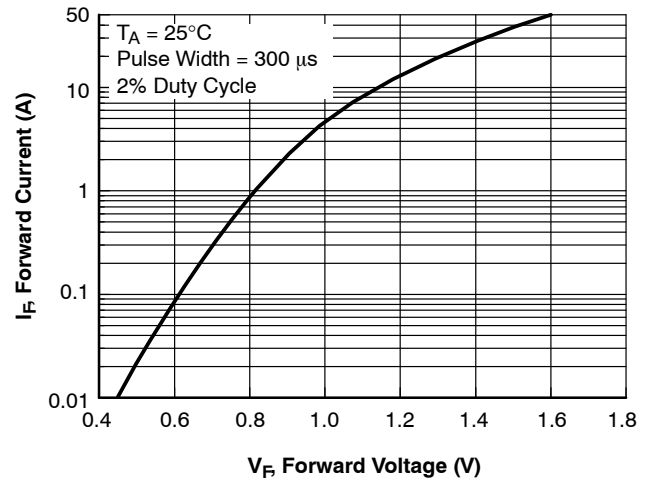


Figure 2. Forward Voltage Characteristics

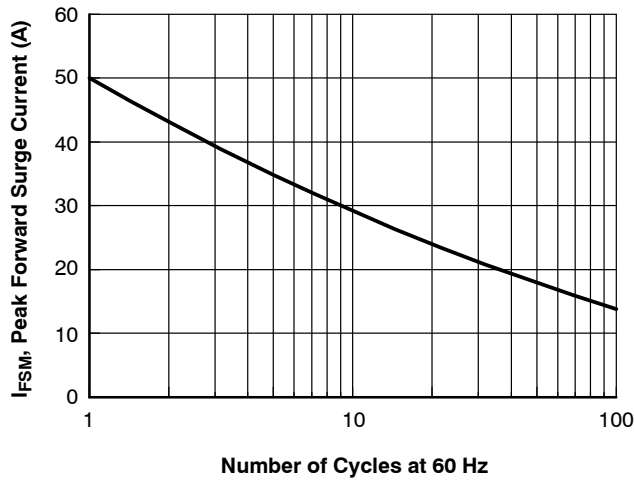


Figure 3. Non-Repetitive Surge Current

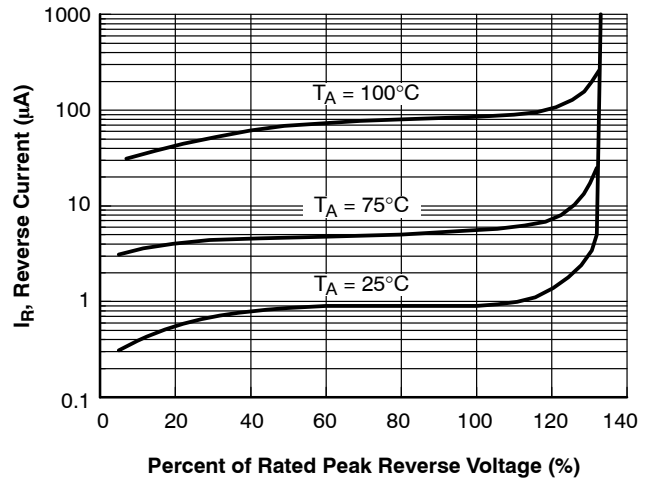


Figure 4. Reverse Current vs. Reverse Voltage

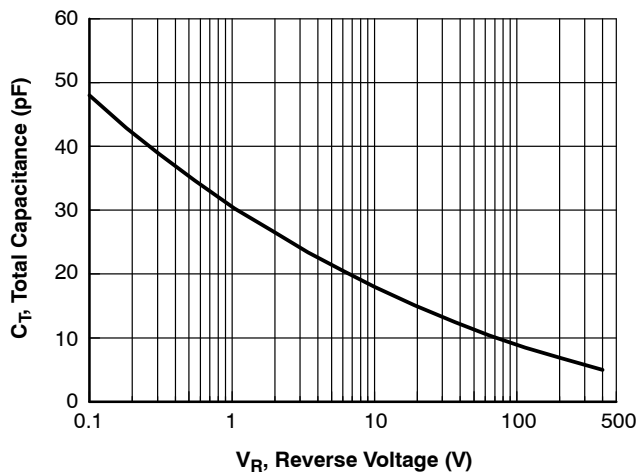
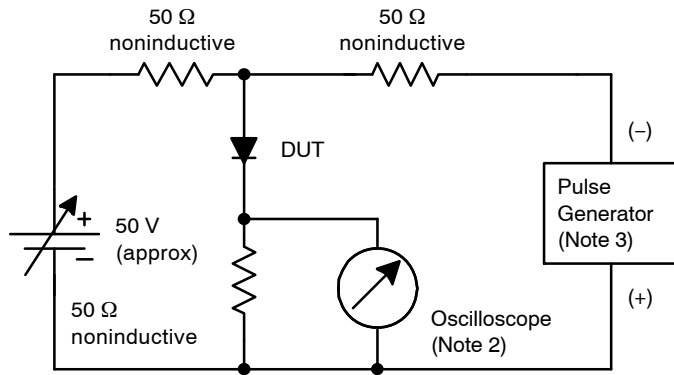


Figure 5. Total Capacitance

ES2A–ES2D



NOTES:

2. Rise time = 7.0 ns max; Input impedance = 1.0 MΩ 22 pF.
3. Rise time = 10 ns max; Source impedance = 50 Ω.

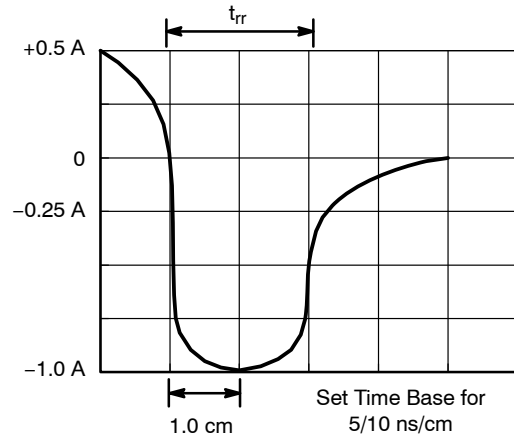


Figure 6. Reverse Recovery Time Characteristic and Test Circuit Diagram

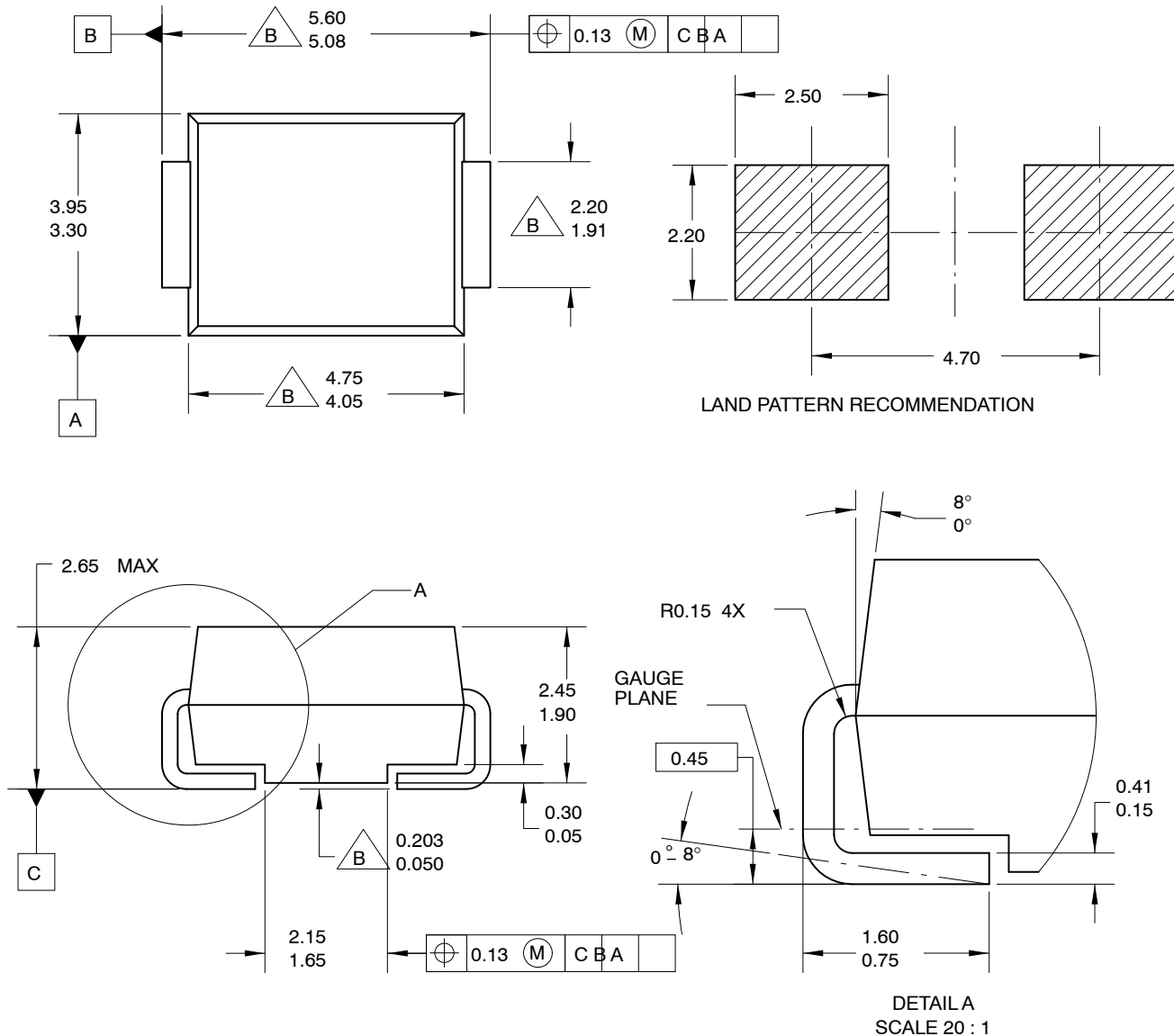
ORDERING INFORMATION

Part Number	Device Code Marking	Package Type	Shipping†
ES2A	ES2A	SMB (Pb-Free)	3000 / Tape & Reel
ES2B	ES2B	SMB (Pb-Free)	3000 / Tape & Reel
ES2C	ES2C	SMB (Pb-Free)	3000 / Tape & Reel
ES2D	ES2D	SMB (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

SMB
CASE 403AF
ISSUE O

DATE 31 AUG 2016



NOTES:

- A. EXCEPT WHERE NOTED CONFORMS TO JEDEC DO214 VARIATION AA.
 B. DOES NOT COMPLY JEDEC STD. VALUE.
 C. ALL DIMENSIONS ARE IN MILLIMETERS.
 D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
 E. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994.
 F. LAND PATTERN STD. DIOM5336X240M.

DOCUMENT NUMBER:	98AON13441G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SMB	PAGE 1 OF 1

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative